EFC4626R



N-Channel Power MOSFET 24V, 5A, 46.2mΩ, Dual EFCP

Features

• 2.5V drive

- Common-drain type
- Protection diode in
- 2KV ESD HBM
- Halogen free compliance

Applications

• Lithium-ion battery charging and discharging switch

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Value	Unit
Source to Source Voltage	V _{SSS}		24	V
Gate to Source Voltage	V _{GSS}		±10	V
Source Current (DC)	IS		5	Α
Source Current (Pulse)	I _{SP}	PW≤10μs, duty cycle≤1%	60	Α
Total Dissipation	PT	When mounted on ceramic substrate (5000mm ² ×0.8mm)	1.4	W
Junction Temperature	Тј		150	°C
Storage Temperature	Tstg		- 55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Thermal Resistance Ratings

Parameter	Symbol	Value	Unit
Junction to Ambient	$R_{\theta JA}$	84	°C /W
When mounted on ceramic substrate (5000mm ² ×0.8mm)			

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions Value min typ			Unit		
Faiametei	Symbol			min	typ r	max	Offic
Source to Source Breakdown Voltage	V(BR)SSS	I _S =1mA, V _{GS} =0V	Test Circuit 1	24			V
Zero-Gate Voltage Source Current	ISSS	V _{SS} =20V, V _{GS} =0V	Test Circuit 1			1	μΑ
Gate to Source Leakage Current	IGSS	VGS=±8V, VSS=0V	Test Circuit 2			±1	μΑ
Gate Threshold Voltage	V _{GS} (th)	V _{SS} =10V, I _S =1mA	Test Circuit 3	0.5		1.3	V
Forward Transconductance	9FS	V _{SS} =10V, I _S =2A	Test Circuit 4		7		S

Continued on next page.

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

EFC4626R

Continued from preceding page.

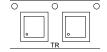
Parameter	Symbol	Conditions		Value			Unit
Farameter	Symbol			min	typ	max	Offic
Static Source to Source On-State Resistance	Rss(on)1	I _S =2A, V _{GS} =4.5V	Test Circuit 5	29.2	37.5	46.2	mΩ
	RSS(on)2	I _S =2A, V _{GS} =4.0V	Test Circuit 5	30.8	39.5	48.6	mΩ
	Rss(on)3	I _S =2A, V _{GS} =3.8V	Test Circuit 5	32.0	41.0	50.5	mΩ
Resistance	RSS(on)4	I _S =2A, V _{GS} =3.1V	Test Circuit 5	35.5	45.5	58.3	mΩ
	Rss(on)5	I _S =2A, V _{GS} =2.5V	Test Circuit 5	42.6	54.0	72.4	mΩ
Turn-ON Delay Time	t _d (on)	V _{SS} =10V, V _{GS} =4.5V, I _S =2A Test Circuit 6			20		ns
Rise Time	t _r				350		ns
Turn-OFF Delay Time	t _d (off)				22000		ns
Fall Time	tf				38400		ns
Total Gate Charge	Qg	VSS=10V, VGS=4.5V, IS=5A	Test Circuit 7		7.5	·	nC
Forward Source to Source Voltage	V _F (S-S)	I _S =2A, V _{GS} =0V	Test Circuit 8		0.81	1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

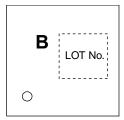
Ordering & Package Information

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Device	Package	Shipping	note					
EFC4626R-TR	EFCP	8,000 pcs. / reel	Pb-Free and Halogen Free					

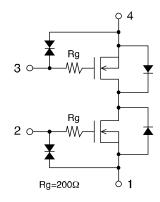
Packing Type: TR



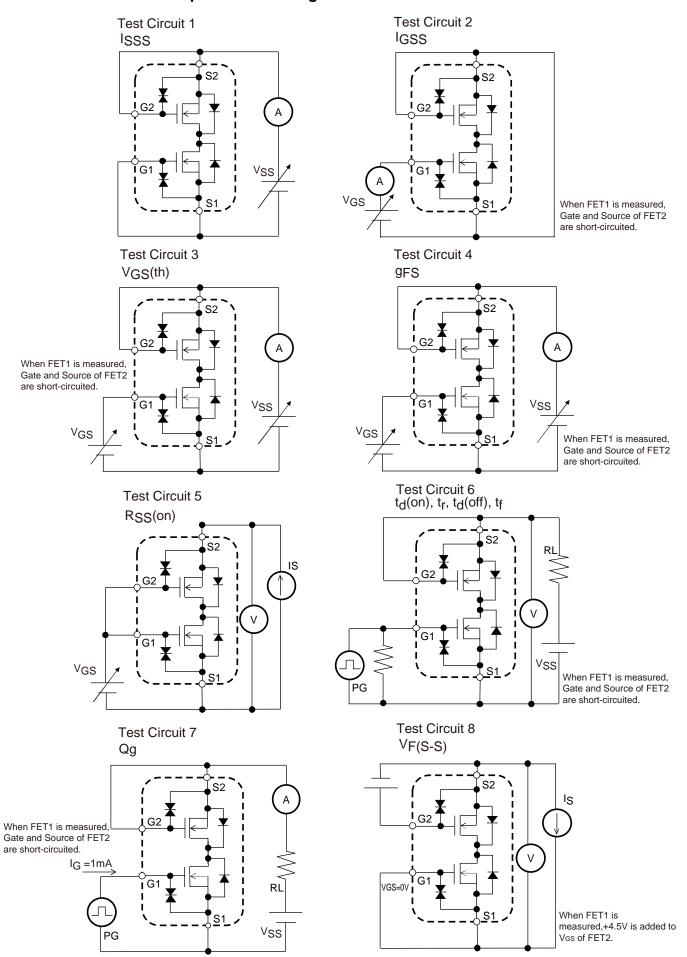
Marking



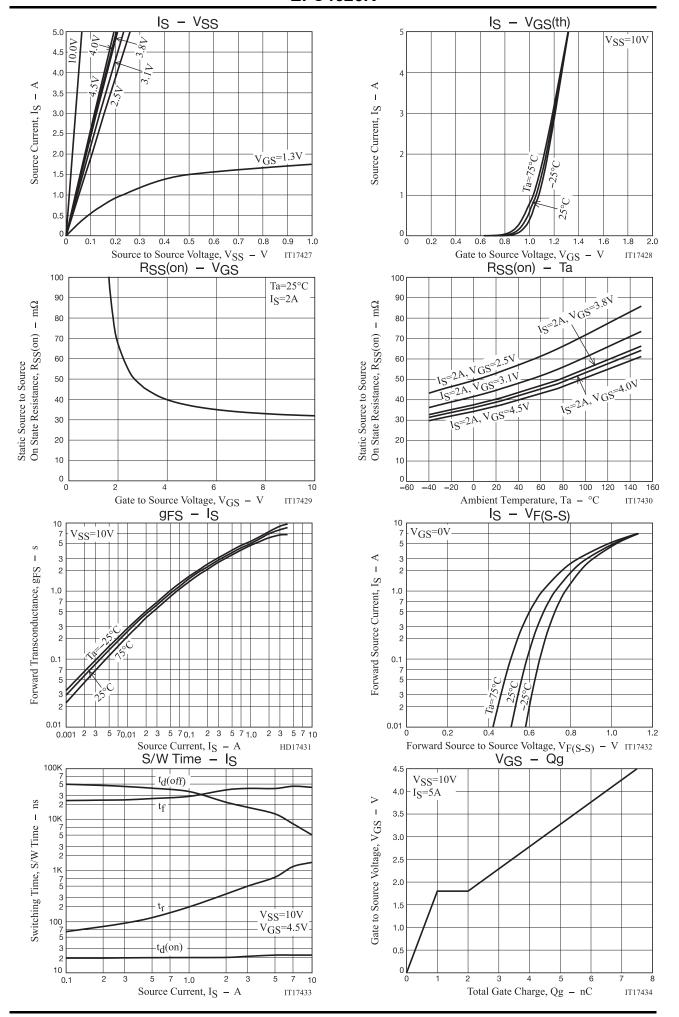
Electrical Connection

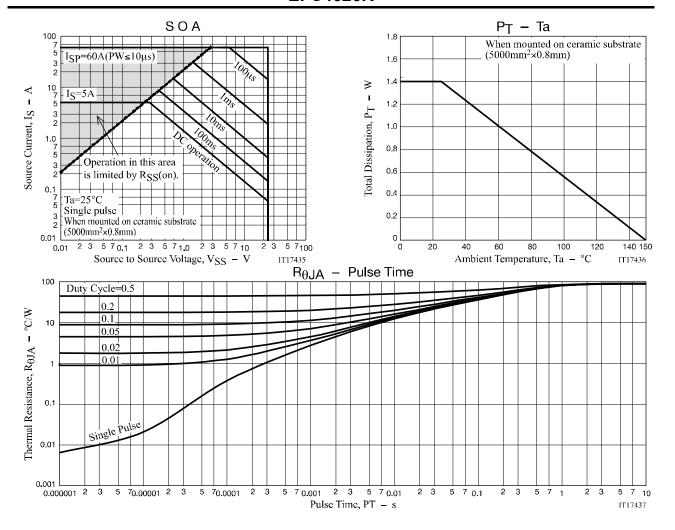


Test circuits are example of measuring FET1 side



When FET2 is measured, the position of FET1 and FET2 is switched.





Package Dimensions

EFC4626R-TR

EFCP1010-4DG-020

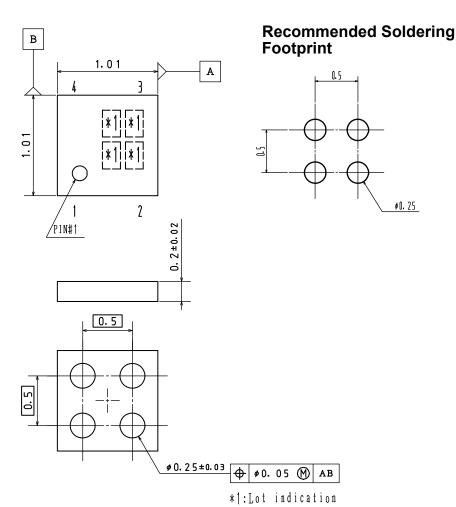
unit: mm

1: Source1

2: Gate1

3: Gate2

4: Source2



Note on usage: Since the EFC4626R is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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